Gain Enhancement of a Wide Slot Antenna Using a Second-Order Bandpass Frequency Selective Surface

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Abstract. Gain enhancement of a wide slot antenna over a wide frequency band using a low profile, second order bandpass frequency selective surface (FSS) as a superstrate is presented in this paper. The proposed multilayered FSS with non-resonant unit cells in each layer allows inphase transmission of waves radiated from the antenna over a 3dB bandwidth of about 50%. The design allows an enhancement of up to 4 dBi in the antenna gain over the entire frequency band (5-8 GHz) of operation. The FSS provides a very low insertion loss between the two transmission poles along with a linearly decreasing transmission phase over the band. The composite structure shows an impedance bandwidth (-10 dB) of 65% with an average gain between 6-8 dBi over the frequency band with a peak gain of 9 dBi. Measurement results of the fabricated prototype matches well with the predicted values.

Keywords

Wide slot, Frequency Selective Surface, gain, bandpass, superstrate.

1. Introduction

With the increasing demand of high data transmission rates, short pulse transmission and easy integration with the feed networks or MMICs, wide band and ultra-wide band (UWB) slot antennas are being widely used in the communication systems and have become a great interest of researchers. These antennas find applications in ground penetrating radar (GPR), medical imaging, multimedia communications, etc. [1]. Till date several methods have been proposed for widening the bandwidth of slot antennas [2], [3]. In general, these antennas radiate in both directions orthogonal to the radiating plane whereas applications involving line-of-sight (LOS) communication and high signal to noise ratio (SNR) require a directional or semiomnidirectional (wide-beam) radiation patterns. Directional radiation from the antenna also provides enhanced gain in the broadside direction along with reduced side lobe levels (SLL) [4] finding its application in the radar and millimeter wave systems. Enhancement of gain or directivity of these antennas in a specific direction over a wide band of frequencies is a challenging job and very few movements have been made so far in this regard. A broadside seriesfed printed antenna array with a large slot in the ground plane was introduced [4] leading to enhancement in the gain by about 2-3 dB over the whole frequency band but a reasonable increase in the antenna size was required due to the array structure.

Recently, Frequency Selective Surfaces (FSS) are being used in the form of substrates or superstrates [5–11] for the enhancement of antenna performances. Metal type FSS superstrates are much easier to fabricate than the dielectric type. Alireza Foroozesh et al. presented a cavity resonance antenna (CRA) [6], where a patch type FSS has been used as superstrate at a distance of around half wavelength with respect to center frequency from the antenna and both gain and directivity have been efficiently enhanced over the impedance bandwidth. Abbas Pirhadi et al. have investigated an electromagnetic bandgap (EBG) antenna [7] where a FSS with square loop elements was used as superstrate above the microstrip patch, leading to enhanced directivity and wide bandwidth. A technique for achieving highest possible gain for a patch antenna at the resonating frequency was proposed [8] where a magnetic material (relative permeability 50) was used as superstrate with less than conventional half wavelength spacing. The use of FSS superstrates for dual-band directivity enhancement was introduced by Lee et al. [9] that comprise two FSS screens with about half wavelength spacing between them at a height of about half wavelength from the antenna which makes the overall height almost one wavelength and it is to be reduced for low profile applications.

In this paper, a thin multilayered FSS structure has been used as superstrate above a wide slot antenna to enhance the gain in broadside direction over the entire frequency band of operation. The FSS, exhibiting band pass filtering property, consists of two thin dielectric sheets and three metallic layers. In Sec. 2, design strategy of the FSS layers and the slot antenna have been discussed separately. In Sec. 3 the FSS-antenna composite structure is investigated in terms of reflection coefficient, radiation pattern and gain vs. frequency characteristics. Simulation and measurement results are presented in each case.

2. Antenna-FSS Configuration

The proposed structure is composed of a wide slot antenna and a FSS superstrate as shown in Fig. 1 and Fig. 2 showing its side view and three dimensional views.

2.1 Design of the Wide Slot Antenna

A simple design of a microstrip line fed slot antenna was proposed by Jen-Yea Jan et al. [12] where a square shaped slot was chosen in the ground plane with a specific angle of rotation to excite two close resonant frequencies leading to a wide bandwidth. Following this procedure, a slot antenna is designed in the frequency band of 5-8 GHz for the purpose of gain enhancement over the entire operating band. Length of the slot determines the first resonating frequency and these slots radiate like a half wave dipole whose length is half of the wavelength corresponding to the resonating frequency. So for exciting the first resonance near 5.7 GHz, size of the slot has been chosen half of the guided wavelength corresponding to 5.7 GHz and is given in the following equation:

Slot length=
$$\frac{C_0}{2f_r \sqrt{(\varepsilon_r + 1)/2}}$$
 (1)

where C_0 is the speed of light in free space (3×10⁸ m/s), f_r is the desired resonating frequency (5.7 GHz) and ε_r



Fig. 1. Geometry of the FSS-antenna composite structure (side view).



Fig. 2. Three dimensional view of the slot antenna with FSS (all dimensions are in mm).

 $(\varepsilon_r = 4.4$ for FR4) is the relative permittivity of the substrate. The substrate thickness is $h_s = 1.6$ mm. The above equation gives a slot length of 16 mm. To achieve the second resonance near 7.5 GHz, the slot has been rotated at an angle of 45° about y axis and for optimal matching, length of the microstrip feed line has been chosen to be 18.5 mm.

2.2 Design Principle of the FSS Layers

A low profile FSS structure offering second order band pass filtering property, has been used as a superstrate layer above the antenna for the purpose of gain enhancement. The second order band pass response has been achieved by cascading three FSS layers of patch-aperturepatch type with FR4 as the dielectric material ($\varepsilon_r = 4.4$) in between them as shown in Fig. 2. Unit cells of the patch and aperture type layers exhibiting capacitive and inductive properties respectively are also shown in the figure. They do so due to their non-resonant nature, where dimensions of the unit cells are much smaller than the wavelength corresponding to resonating frequency. Fig. 2 shows top view of each layer, where P_X and P_Y are horizontal and vertical periodicities of the unit cells same for both types of FSS screens and (P-s) is dimension of the patch in capacitive layer (s being the spacing between individual patches and $P_X = P_Y = P$). Inductive wire grids in the middle layer have a grid width of w. With the fact that periodicities of the unit cells in each layer are same in X and Y directions, the FSS structure is polarization independent with respect to the plane wave incident on it.

A simple equivalent circuit of the FSS is given in Fig. 3(a), valid for normal incidence of the electromagnetic wave. Being non-resonant in nature, the first and third patch type layers are modeled as parallel capacitors C_1 and C_3 , whereas the middle aperture type grid layer is modeled as a parallel inductor L_2 . Dielectric substrates separating the metallic FSS layers of height h_U and h_L can be modeled



Fig. 3. (a) Simple equivalent circuit model of the cascaded FSS. (b) Second order coupled resonator filter with π network (L₁, L_m and L₃) representation of T network (L_{S1}, L₂ and L_{S2}).

as two short pieces of transmission lines of characteristic impedances $Z_0/\sqrt{\varepsilon_{r1}}$ and $Z_0/\sqrt{\varepsilon_{r2}}$ respectively, where ε_{r1} and ε_{r2} are dielectric constants of the substrates and $Z_0 = 377 \Omega$ is the free space impedance. The transmission line sections are represented here by their equivalent circuit model with a series inductor and a shunt capacitor. Half spaces on both ends of the cascaded FSS are modeled here as semi-infinite transmission lines with characteristic impedances of Z_0r_1 and Z_0r_2 respectively ($r_1=r_2=$ normalized source and load impedances = 1). Second order nature of the filter is clearly visible in the circuit as shown in Fig. 3(b) where T network (consisting of L_{S1} , L_2 and L_{S2}) of the circuit in Fig. 3(a) is converted into a π network (consisting of L_1 , L_m and L_3). The values of L_1 , L_2 and L_{S2} .

For the second order coupled resonator filter of Butterworth type response chosen, different parameters can be obtained from [14] and are given in Tab. 1.

Filter Type	Normalized loaded quality factors		Normalized coupling coefficient	Normalized impedances	
	q_1	q_2	<i>k</i> ₁₂	Source (r_1)	Load (r_2)
Butterworth	1.4142	1.4142	0.70711	1	1

Tab. 1. Different parameters for Butterworth filter response.

From the desired values of center frequency f_0 and fractional bandwidth $\delta' (= BW/f_0$ corresponding to 3 dB transmission bandwidth) along with the parameters provided in Tab. 1, the value of inductor L_2 in the circuit of Fig. 3(a) can be found by the following equation [13]:

$$L_{2} = \frac{Z_{0}}{(2\pi f_{0})k_{12}} \cdot \frac{(k_{12}\delta)^{2}}{1 - (k_{12}\delta)^{2}} \cdot \sqrt{\frac{r_{1}r_{2}}{q_{1}q_{2}}}.$$
 (2)

Using Telegrapher's model for TEM transmission lines, the inductors L_{S1} and L_{S2} representing the short transmission line sections of the circuit in Fig. 3(a) can be calculated from the following equations:

$$L_{S1} = \mu_0 \mu_{r1} h_U, \qquad (3)$$

$$L_{S2} = \mu_0 \mu_{r2} h_L \,. \tag{4}$$

The values of capacitors C_1 and C_3 representing the capacitive (patch) layers of FSS can also be obtained from the following equations [13]:

$$C_1 = \frac{q_1}{\left(2\pi f_0\right) Z_0 r_1 \delta} - \frac{\varepsilon_0 \varepsilon_{r_1} h_U}{2}, \qquad (5)$$

$$C_3 = \frac{q_2}{(2\pi f_0)Z_0 r_2 \delta} - \frac{\varepsilon_0 \varepsilon_{r_2} h_L}{2}.$$
 (6)

The second terms in the above equations represent the capacitors C_{S1} and C_{S2} of the short transmission line sections of the circuit in Fig. 3(a). For the proposed design, FR4 (glass-epoxy) has been chosen as the substrate material, for which $\varepsilon_{r1} = \varepsilon_{r2} = \varepsilon_r = 4.4$ and $\mu_{r1} = \mu_{r2} = \mu_r = 1$ (the dielectric substrate being non-magnetic).

The above equations along with the substrate parameters are now used to determine the inductor (L_2) and capacitor (C_1 , C_3) values of the Butterworth filter for desired response of FSS with center frequency $f_0 = 6.5$ GHz (of the frequency band 5-8 GHz) and fractional bandwidth $\delta = 0.46$ (BW = 3 GHz). For available substrate thickness $h_U = h_L = 0.8$ mm, the computed values are $C_1 = C_3 =$ 184.4 fF and $L_2 = 1.1$ nH. In the next step, dimensions of the unit cells of both the capacitive and inductive layers of the FSS are determined by the following equations [13].

$$C_1 = C_3 = C = \varepsilon_0 \varepsilon_{\text{eff}} \frac{2P}{\pi} \ln \left(\sin \frac{\pi s}{2P} \right)^{-1}, \tag{7}$$

$$L_{2} = L = \mu_{0} \mu_{\text{eff}} \frac{P}{2\pi} \ln \left(\sin \frac{\pi w}{2P} \right)^{-1}.$$
 (8)

From (7), with C = 184.4 fF, s = 0.3 mm, ε_0 (free space permittivity) = 8.85×10^{-12} F/m and ε_{eff} (effective permittivity of the medium in which the patches are located) = $(\varepsilon_r + 1)/2 = 2.7$, the unit cell dimension *P* is first obtained. The spacing between consecutive patches (*s*) is selected so to avoid fabrication errors, at the same time allowing good angular stability [15]. Then with the value of *P*, *L* = 1.1 nH, μ_0 (free space permeability) = $4\pi \times 10^{-7}$ H/m and μ_{eff} (effective permeability of the medium in which the inductive grids are located) = $(\mu_r + 1)/2 = 1$, width of the inductive wire grids is determined.

With the initially available dimensions of unit cells of the FSS layers, after a few successive full wave EM simulations, optimal dimensions are obtained and are given in Tab. 2 along with the values obtained from circuit model for the desired second order bandpass response. For EM simulations, HFSS is used.

Parameter	$P_X = P_Y = P$	w	S	$h_U = h_L$
Circuit model	5.1 mm	1.1 mm	0.3 mm	0.8 mm
Optimized	7 mm	1.6 mm	0.3 mm	0.8 mm

Tab. 2. Calculated and optimal dimensions of FSS unit cells.

2.3 Principle of Operation

Principle of operation of the composite structure can be well understood with the help of Fig. 1 and Fig. 4. The process of gain enhancement of the wide slot antenna can be justified with the phase vs. frequency characteristics of FSS and the composite structure. As discussed previously, the FSS is designed to exhibit bandpass characteristics in the frequency range of 5-8 GHz and as can be seen from the transmission phase (φ_T as shown in Fig. 1) response of the cascaded FSS structure in Fig. 4(b), the phase decreases linearly with frequency within the desired frequency band.

As can be observed from Fig. 1, waves radiated by the slot suffer a small amount of reflection from the lower metallic (patch) layer of the FSS and again get reflected by the ground plane, and phase delay of this round trip propagation (φ_R as shown in Fig. 1) increases linearly with frequency as given by equation (9) below.

$$\varphi_R = 2\frac{2\pi f}{c}H.$$
 (9)

The variation of φ_R with frequency is controlled by the spacing *H* between antenna and FSS to produce a coherent wave from the composite structure with a zero phase variation (total phase $\varphi = \varphi_T + \varphi_R$). The waves from the structure thus go through a constructive interference of its components leading to an enhancement in gain over the entire frequency band.

3. Characteristics of the Antenna with FSS Superstrate

In the analysis of the proposed design, first antenna and FSS layers are investigated separately followed by the composite structure. Both simulation and measurement results are presented.

3.1 Characteristics of the FSS Layers

To analyze with HFSS, unit cells of the three FSS layers are placed inside a waveguide with master-slave boundaries on the four sides with a floquet port excitation given. Transmission and reflection coefficients of the structure are then obtained using full wave EM simulation and are shown in Fig. 4(a) with the transmission phase (degree) variation with frequency in Fig. 4(b).

As can be observed from Fig. 4(a), the FSS exhibits a pass band over 5-8 GHz with transmission level above





Fig. 4. (a) Simulated transmission and reflection coefficient of the FSS, (b) EM simulation of transmission phase of the FSS structure.

-3 dB with two transmission poles. From the phase vs. frequency plot, it is clear that, the phase is zero at both the transmission poles and has nearly linear variation with frequency in between. The FSS in its pass band gives an insertion loss of less than 1 dB at both the transmission poles and about 2.8 dB near the center frequency 6.5 GHz. Higher loss tangent (0.02) of FR4 in comparison to conventional microwave substrates accounts for this insertion loss. The 3 dB transmission as well as reflection bandwidth of the bandpass FSS is around 50% with respect to the center frequency.

3.2 Characteristics of the Antenna with FSS

Fabricated prototypes of the FSS layers (patch and aperture type) and slot antenna along with the composite structure are shown in Fig. 5. Dimensions of the fabricated structure are also given below the figure.







Fig. 6. (a) Simulated reflection coefficient of antenna without and with FSS at different height H. (b) Simulated and measured reflection coefficient of the antenna with FSS at H = 29 mm.

It can be clearly observed that for the fabricated prototype, dimensions of the overall structure as well as the sub-structures are well below the wavelength (λ_0) corresponding to the center frequency of operation (6.5 GHz). Unit cell dimensions of the FSS layers (P_X and P_Y) are on the order of 0.15 λ_0 , whereas thickness of the FSS superstrate ($h_U + h_L$) is only 0.03 λ_0 . Dimension of the slot in the ground plane of the antenna is 0.3 λ_0 .

Simulated reflection coefficients (dB) of the antenna with and without FSS are shown in Fig. 6(a) for different values of *H*. The height *H* is initially kept at $\lambda_0/2$ (λ_0 corresponding to the first resonating frequency) which is around 27 mm and then slightly varied between 25 mm and 31 mm. The antenna with FSS placed at an optimum height of 29 mm is verified experimentally and the result is shown in Fig. 6(b) along with the simulated one. S parameter measurement has been carried out with Agilent Network Analyzer E5071B, ENA series. The measured impedance bandwidth with the FSS is 65% which compares well with the predicted value of 62%. A slight deviation between the two results occurs due to fabrication error and a gap mismatch between antenna and FSS.

Radiation pattern measurements of the antenna with FSS at a height H = 29 mm have been carried out with a microwave signal generator HMC-T2100 (10 MHz-20 GHz) and a power meter JPSS 9000B. Simulated and measured normalized radiation patterns for co- and cross-



Fig. 7. Simulation and measurement results of co and cross polarization of normalized radiation patterns for E and H planes of the antenna with and without FSS at 6.32 GHz.

polarizations in E and H planes are shown in Fig. 7 for 6.32 GHz. Radiation patterns for the antenna without FSS are also given in Fig. 7 for comparison and it can be observed that, with the use of FSS, gain enhanced in the broadside direction, while reducing the back lobe levels greatly.

It can be observed from the radiation patterns of the antenna without and with FSS, that the radiation becomes more directive and narrow in the broadside direction with the use of superstrate due to its angular filtering property. As explained in Sec. 2.3 (principle of operation), phase variation of the waves radiated from the structure in the broadside direction becomes zero over 5-8 GHz due to the opposite nature of transmission (φ_T) and rotational reflection phase (φ_R) variation with frequency. So the constructive interference of radiated waves occurs mainly in the broadside direction (near $\theta = 0^\circ$) leading to enhanced radiation and gain, whereas in the other directions (much beyond $\theta = 0^\circ$) they interfere destructively leading to reduced radiation levels. So, the radiation pattern gets more directive and narrowed.

Radiation from E plane offers an average difference of around 30 dB between the co and cross polar components, whereas for the H plane radiation, this difference is about 20 dB. Measured gain of the slot antenna with FSS superstrate at H = 29 mm is shown in Fig. 8(a) with the simulated gain with and without FSS also plotted for comparison. It can be observed that the proposed bandpass FSS



Fig. 8. (a) Simulated and measured gain of the slot antenna with and without FSS at *H* of 29 mm. (b) Variation of gain of the slot antenna with the FSS at different height *H*.

through constructive interference efficiently enhances gain of the antenna in broadside direction of radiation over the entire frequency band.

A measured gain of around 9 dBi is noticed at 6.4 GHz, whereas the gain is maintained between 6-8 dBi over the entire band. A gain enhancement of 2-4 dBi has been achieved between 5.5-7.5 GHz and less for the rest of the frequency band (5-8 GHz). Simulated results of gain variation for the antenna with FSS placed at different heights (H) are shown for comparison in Fig. 8(b).

4. Conclusions

A second order, band pass frequency selective surface with large bandwidth combined with a wideband slot antenna has been studied and demonstrated successfully. The structure is low profile because of non-resonant nature of the patch and grid type FSS layers. The proposed design achieves an impedance bandwidth of 65% and an average gain of 6-8 dBi over the operating frequency band of the antenna with a peak gain of 9 dBi. With the use of proposed superstrate, gain of the antenna is enhanced only in the desired frequency band and has a nearly sharp fall outside the band. The design also allows a variation of gap between the antenna and superstrate by around 4 mm without significant degradation in its performance. The use of FSS as a shield allows the antenna to be used in close proximity of conductors without significant interference electromagnetic waves. The gap between FSS layers and the slot antenna is yet to be reduced for the purpose of further miniaturization.

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